

### BIDIRECTIONAL THYRISTOR OVERVOLTAGE PROTECTORS

# **9ELx Primary Protector Series**

### Ion-Implanted Breakdown Region

- Precise and Stable Voltage
- Low Voltage Overshoot under Surge

	Device	V <sub>(BR)</sub> Minimum V	V <sub>(BO)</sub> Minimum V	V <sub>(BO)</sub> Maximum V
ſ	9EL2	±245	±265	±400
ſ	9EL3		±200	±265

### **Rated for International Surge Wave Shapes**

Device	ITU-T K28 (10/700) I <sub>TSP</sub> A	GR-974-CORE (10/1000) I <sub>TSP</sub> A
9EL2	±200	±150
9EL3	±125	±100

### Gas Discharge Tube (GDT) Replacement

Planar Passivated Junctions in a Protected Cell Construction

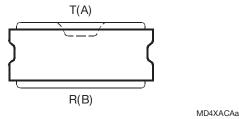
- Low Off-State Current
- -Extended Service Life

### **Soldered Copper Electrodes**

- High Current Capability
- Cell Construction Short Circuits Under Excessive Current Conditions



## Cell Package (Side View)



### **Device Symbol**



1

Terminals T and R correspond to the alternative line designators of A and B

### Description

These devices are primary protector components for semiconductor arrester assemblies intended to meet the generic requirements of Telcordia GR-974-CORE or ITU-T Recommendation K28 (03/93). To conform to the specified environmental requirements, the 9ELx must be installed in a housing which maintains a stable microclimate during these tests (e.g. FIGURE I.1/K28).

The protector consists of a symmetrical voltage-triggered bidirectional thyristor. Overvoltages are initially clipped by breakdown clamping until the voltage rises to the breakover level, which causes the device to crowbar into a low-voltage on state. This low-voltage on state causes the current resulting from the overvoltage to be safely diverted through the device. In usual applications, the high crowbar holding current prevents d.c. latchup as the diverted current subsides. This 9ELx range consists of two voltage variants to meet various maximum system voltage levels. They are designed to voltage limit and withstand the listed international lightning surges in both polarities.

These monolithic protection devices are constructed using two nickel plated copper electrodes soldered to each side of the silicon chip. This packaging approach allows heat to be removed from both sides of the silicon, resulting in the doubling of the devices thermal capacity, enabling a power line cross current capability of 10 A rms for 1 second. One of the 9ELx's copper electrodes is specially shaped to promote a progressive shorting action (at 50/60 Hz currents greater than 60 A). The assembly must hold the 9ELx in compression, so that the cell electrodes can be forced together during overstress testing. Under excessive power line cross conditions the 9ELx will fail short circuit, providing maximum protection to the equipment.

# **9ELx Primary Protector Series**

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# Absolute Maximum Ratings, T<sub>A</sub> = 25 °C (Unless Otherwise Noted)

Rating		Symbol	Value	Unit
Non-repetitive peak on-state pulse current (see Notes 1 and 2)				
5/310 μs (ITU-T K28, 10/700 μs voltage wave shape)	9EL2 -20 °C to 65 °C		200	
	9EL3 0 °C to 65 °C	l <sub>TOD</sub>	125	А
10/1000 μs (GR-974-CORE, 10/1000 μs voltage wave shape)	9EL2 -20 °C to 65 °C		150	
	9EL3 0 °C to 65 °C		100	
Non-repetitive peak on-state current (see Note 1)				
full ains ways 50/60 Hz 1 a	9EL2 -40 °C to 65 °C	I <sub>TOM</sub>	10	A rms
full sine wave, 50/60 Hz, 1 s	9EL3 0 °C to 65 °C		10	
Junction temperature		T <sub>J</sub>	-40 to +150	°C
Storage temperature range		T <sub>stg</sub>	-40 to +150	°C

NOTES: 1. The surge may be repeated after the device has returned to thermal equilibrium.

2. Most PTTs quote an unloaded voltage waveform. In operation the 9ELx essentially shorts the generator output The resulting loaded current waveform is specified.

### Electrical Characteristics for the R and T Terminals, T<sub>A</sub> = 25 °C (Unless Otherwise Noted)

	Parameter	Test Conditions			Min	Тур	Max	Unit
V <sub>(BR)</sub>	Breakdown Voltage	I <sub>(BR)</sub> = ±20 mA, (see Note 3)	9EL2	-40 °C to 65 °C	±245			V
		$dv/dt = \pm 0.2 \text{ V/s},  R_{SOURCE} > 200$	9EL2	9EL2 +15 °C to 25 °C -40 °C to 65 °C	±265		±400	
V <sub>(BO)</sub>			9EL3	+15 °C to 25 °C	±200			V
		100.1/	051.0	0 °C to 65 °C			±265	
V <sub>(BO)</sub>	Impulse breakover	100 V/μs $\leq$ dv/dt $\leq$ ±1000 V/μs,	9EL2	-40 °C to 65 °C			±400	V
(BO)	voltage	di/dt ≤ 10 A/μs	9EL3	0 °C to 65 °C			±350	
	Impulse reset	Sources are 52.5 V O.C., 260 mA S.C. and 135 V O.C., 200 mA S.C.	9EL2 9EL3	-40 °C to 65 °C 0 °C to 65 °C			20 20	ms
		on-state current 25 A, 10/1000 μs impulse	JLLO	0 0 10 00 0			20	
	Off-state current	V <sub>D</sub> = ±50 V (see Note 4)	9EL2	-40 °C to 65 °C			±0.5	
		V <sub>D</sub> = ±30 V (See Note 4)	9EL3	0 °C to 65 °C			±0.5	^
ID		V 000 V	9EL2	-40 °C to 65 °C			±10	μА
		$V_D = \pm 200 \text{ V}$	9EL3	+15 °C to 25 °C			±1	
C	Off-state capacitance	$f = 1 \text{ MHz},  V_d = 1 \text{ Vrms}, V_D = 0,$	9EL2	-40 °C to 65 °C			150	pF
C <sub>off</sub>	On-state capacitance	$v_d = v_{\text{IIIIS}},  v_d = v_{\text{IIIIIS}},  v_d = v_{\text{IIIIS}},  v_d = v_{\text{IIIIIS}},  v_d = v_{\text{IIIIS}},  v_d = v_{\text{IIIIIS}},  v_d = v_{\text{IIIIIIIS},  v_d = v_{\text{IIIIIS}},  v_d = v_{\text{IIIIIIS}},  v_d = v_{\text{IIIIIIS}},  v_d = v_{\text{IIIIIIS}},  v_d = v_{\text{IIIIIIS}},  v_d = v_{\text{IIIIIIII}},  v_d = v_{\text{IIIIIIII}},  v_d = v_{\text{IIIIIIIIII}},  v_d = v_{\text{IIIIIIIIIIIIIIIII},  v_d = v_{IIIIIIIIIIIIIIIIIIIIIIIIIIIIIIIIIII$	9EL3	0 °C to 65 °C			150	ρг

NOTES: 3. Meets Telcordia GR-974-CORE Issue 2, December 1999 - Rated Voltage Test (4.7).

4. This device is sensitive to light. Suggest that this parameter be measured in a dark environment.

### **Parameter Measurement Information**

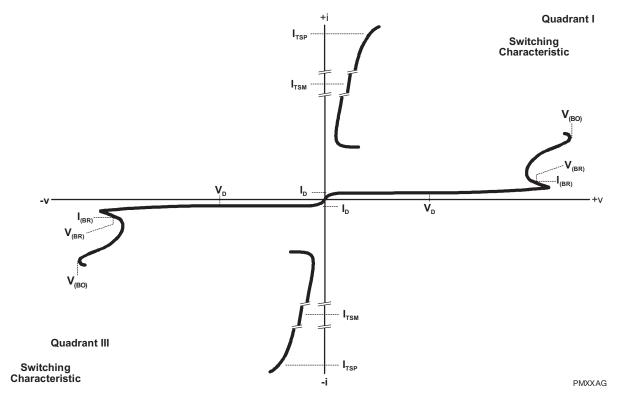
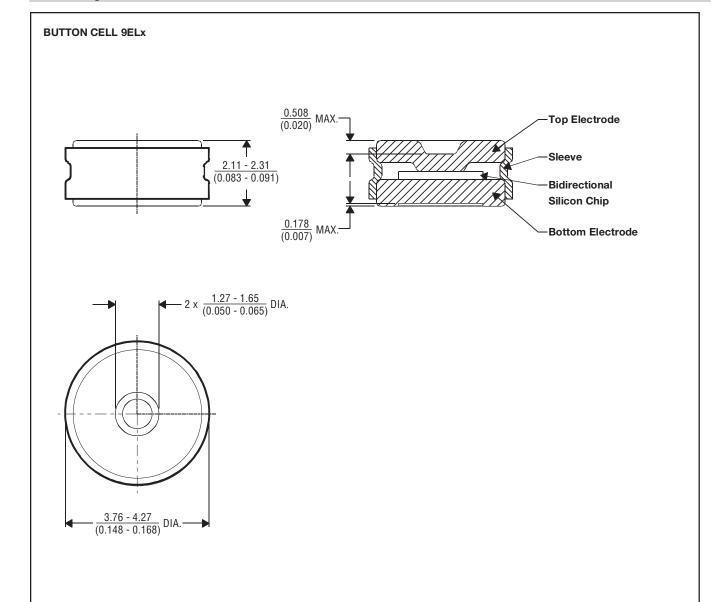


Figure 1. Voltage-Current Characteristic for the T and R Terminals
All Measurements are Referenced to the R Terminal

### **Cell Package**



MDXXAVAa

DIMENSIONS ARE :  $\frac{\text{MILLIMETERS}}{\text{(INCHES)}}$ 

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